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What is "Embedded - Microcontrollers"?

"Embedded - Microcontrollers" refer to small, integrated circuits designed to perform specific tasks within larger systems. These microcontrollers are essentially compact computers on a single chip, containing a processor core, memory, and programmable input/output peripherals. They are called "embedded" because they are embedded within electronic devices to control various functions, rather than serving as standalone computers. Microcontrollers are crucial in modern electronics, providing the intelligence and control needed for a wide range of applications.

Applications of "<u>Embedded - Microcontrollers</u>"

Details	
Product Status	Discontinued at Digi-Key
Core Processor	CIP-51 8051
Core Size	8-Bit
Speed	72MHz
Connectivity	I ² C, SMBus, SPI, UART/USART
Peripherals	Brown-out Detect/Reset, POR, PWM, WDT
Number of I/O	21
Program Memory Size	32KB (32K x 8)
Program Memory Type	FLASH
EEPROM Size	-
RAM Size	2.25K x 8
Voltage - Supply (Vcc/Vdd)	2.2V ~ 3.6V
Data Converters	A/D 13x14b; D/A 4x12b
Oscillator Type	Internal
Operating Temperature	-40°C ~ 105°C (TA)
Mounting Type	Surface Mount
Package / Case	24-SSOP (0.154", 3.90mm Width)
Supplier Device Package	24-QSOP
Purchase URL	https://www.e-xfl.com/product-detail/silicon-labs/efm8lb12f32e-a-qsop24r

1. Feature List

The EFM8LB1 device family are fully integrated, mixed-signal system-on-a-chip MCUs. Highlighted features are listed below.

- · Core:
 - · Pipelined CIP-51 Core
 - · Fully compatible with standard 8051 instruction set
 - 70% of instructions execute in 1-2 clock cycles
 - · 72 MHz maximum operating frequency
- · Memory:
 - Up to 64 kB flash memory (63 kB user-accessible), in-system re-programmable from firmware in 512-byte sectors
 - Up to 4352 bytes RAM (including 256 bytes standard 8051 RAM and 4096 bytes on-chip XRAM)
- Power:
 - · Internal LDO regulator for CPU core voltage
 - · Power-on reset circuit and brownout detectors
- I/O: Up to 29 total multifunction I/O pins:
 - · Up to 25 pins 5 V tolerant under bias
 - · Selectable state retention through reset events
 - · Flexible peripheral crossbar for peripheral routing
 - · 5 mA source, 12.5 mA sink allows direct drive of LEDs
- · Clock Sources:
 - Internal 72 MHz oscillator with accuracy of ±2%
 - Internal 24.5 MHz oscillator with ±2% accuracy
 - Internal 80 kHz low-frequency oscillator
 - · External CMOS clock option
 - · External crystal/RC/C Oscillator (up to 25 MHz)

- Analog:
 - 14/12/10-Bit Analog-to-Digital Converter (ADC)
 - Internal calibrated temperature sensor (±3 °C)
 - 4 x 12-Bit Digital-to-Analog Converters (DAC)
 - · 2 x Low-current analog comparators with adjustable refer-
- · Communications and Digital Peripherals:
 - · 2 x UART, up to 3 Mbaud
 - SPI™ Master / Slave, up to 12 Mbps
 - SMBus[™]/I2C[™] Master / Slave, up to 400 kbps
 - I²C High-Speed Slave, up to 3.4 Mbps
 - · 16-bit CRC unit, supporting automatic CRC of flash at 256byte boundaries
 - 4 Configurable Logic Units
- · Timers/Counters and PWM:
 - 6-channel Programmable Counter Array (PCA) supporting PWM, capture/compare, and frequency output modes
 - 6 x 16-bit general-purpose timers
 - · Independent watchdog timer, clocked from the low frequency oscillator
- · On-Chip, Non-Intrusive Debugging
 - · Full memory and register inspection
 - Four hardware breakpoints, single-stepping

With on-chip power-on reset, voltage supply monitor, watchdog timer, and clock oscillator, the EFM8LB1 devices are truly standalone system-on-a-chip solutions. The flash memory is reprogrammable in-circuit, providing nonvolatile data storage and allowing field upgrades of the firmware. The on-chip debugging interface (C2) allows non-intrusive (uses no on-chip resources), full speed, in-circuit debugging using the production MCU installed in the final application. This debug logic supports inspection and modification of memory and registers, setting breakpoints, single stepping, and run and halt commands. All analog and digital peripherals are fully functional while debugging. Device operation is specified from 2.2 V up to a 3.6 V supply. Devices are AEC-Q100 qualified (pending) and available in 4x4 mm 32-pin QFN, 3x3 mm 24-pin QFN, 32-pin QFP, or 24-pin QSOP packages. All package options are lead-free and RoHS compliant.

2. Ordering Information

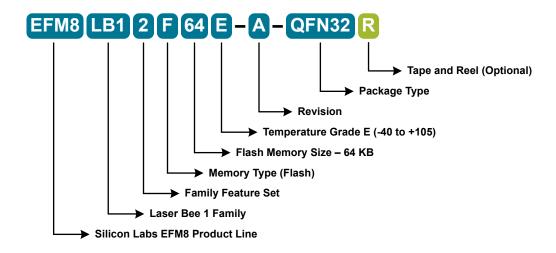


Figure 2.1. EFM8LB1 Part Numbering

All EFM8LB1 family members have the following features:

- · CIP-51 Core running up to 72 MHz
- Three Internal Oscillators (72 MHz, 24.5 MHz and 80 kHz)
- SMBus
- I2C Slave
- SPI
- · 2 UARTs
- 6-Channel Programmable Counter Array (PWM, Clock Generation, Capture/Compare)
- · Six 16-bit Timers
- · Four Configurable Logic Units
- 14-bit Analog-to-Digital Converter with integrated multiplexer, voltage reference, temperature sensor, channel sequencer, and direct-to-XRAM data transfer
- Two Analog Comparators
- · 16-bit CRC Unit
- AEC-Q100 qualified (pending)

In addition to these features, each part number in the EFM8LB1 family has a set of features that vary across the product line. The product selection guide shows the features available on each family member.

Table 2.1. Product Selection Guide

Ordering Part Number	Flash Memory (kB)	RAM (Bytes)	Digital Port I/Os (Total)	ADC0 Channels	Voltage DACs	Comparator 0 Inputs	Comparator 1 Inputs	Pb-free (RoHS Compliant)	Temperature Range	Package
EFM8LB12F64E-A-QFN32	64	4352	29	20	4	10	9	Yes	-40 to +105 °C	QFN32
EFM8LB12F64E-A-QFP32	64	4352	28	20	4	10	9	Yes	-40 to +105 °C	QFP32
EFM8LB12F64E-A-QFN24	64	4352	20	12	4	6	6	Yes	-40 to +105 °C	QFN24
EFM8LB12F64E-A-QSOP24	64	4352	21	13	4	6	7	Yes	-40 to +105 °C	QSOP24

3.2 Power

All internal circuitry draws power from the VDD supply pin. External I/O pins are powered from the VIO supply voltage (or VDD on devices without a separate VIO connection), while most of the internal circuitry is supplied by an on-chip LDO regulator. Control over the device power can be achieved by enabling/disabling individual peripherals as needed. Each analog peripheral can be disabled when not in use and placed in low power mode. Digital peripherals, such as timers and serial buses, have their clocks gated off and draw little power when they are not in use.

Table 3.1. Power Modes

Power Mode	Details	Mode Entry	Wake-Up Sources
Normal	Core and all peripherals clocked and fully operational		
Idle	Core haltedAll peripherals clocked and fully operationalCode resumes execution on wake event	Set IDLE bit in PCON0	Any interrupt
Suspend	Core and peripheral clocks halted HFOSC0 and HFOSC1 oscillators stopped Regulator in normal bias mode for fast wake Timer 3 and 4 may clock from LFOSC0 Code resumes execution on wake event	1. Switch SYSCLK to HFOSC0 2. Set SUSPEND bit in PCON1	Timer 4 Event SPI0 Activity I2C0 Slave Activity Port Match Event Comparator 0 Rising Edge CLUn Interrupt-Enabled Event
Stop	 All internal power nets shut down Pins retain state Exit on any reset source	1. Clear STOPCF bit in REG0CN 2. Set STOP bit in PCON0	Any reset source
Snooze	Core and peripheral clocks halted HFOSC0 and HFOSC1 oscillators stopped Regulator in low bias current mode for energy savings Timer 3 and 4 may clock from LFOSC0 Code resumes execution on wake event	1. Switch SYSCLK to HFOSC0 2. Set SNOOZE bit in PCON1	Timer 4 Event SPI0 Activity I2C0 Slave Activity Port Match Event Comparator 0 Rising Edge CLUn Interrupt-Enabled Event
Shutdown	All internal power nets shut downPins retain stateExit on pin or power-on reset	1. Set STOPCF bit in REG0CN 2. Set STOP bit in PCON0	RSTb pin reset Power-on reset

3.3 I/O

Digital and analog resources are externally available on the device's multi-purpose I/O pins. Port pins P0.0-P2.3 can be defined as general-purpose I/O (GPIO), assigned to one of the internal digital resources through the crossbar or dedicated channels, or assigned to an analog function. Port pins P2.4 to P3.7 can be used as GPIO. Additionally, the C2 Interface Data signal (C2D) is shared with P3.0 or P3.7, depending on the package option.

The port control block offers the following features:

- Up to 29 multi-functions I/O pins, supporting digital and analog functions.
- · Flexible priority crossbar decoder for digital peripheral assignment.
- · Two drive strength settings for each port.
- State retention feature allows pins to retain configuration through most reset sources.
- Two direct-pin interrupt sources with dedicated interrupt vectors (INT0 and INT1).
- · Up to 24 direct-pin interrupt sources with shared interrupt vector (Port Match).

3.8 Reset Sources

Reset circuitry allows the controller to be easily placed in a predefined default condition. On entry to this reset state, the following occur:

- · The core halts program execution.
- Module registers are initialized to their defined reset values unless the bits reset only with a power-on reset.
- · External port pins are forced to a known state.
- Interrupts and timers are disabled.

All registers are reset to the predefined values noted in the register descriptions unless the bits only reset with a power-on reset. The contents of RAM are unaffected during a reset; any previously stored data is preserved as long as power is not lost. By default, the Port I/O latches are reset to 1 in open-drain mode, with weak pullups enabled during and after the reset. Optionally, firmware may configure the port I/O, DAC outputs, and precision reference to maintain state through system resets other than power-on resets. For Supply Monitor and power-on resets, the RSTb pin is driven low until the device exits the reset state. On exit from the reset state, the program counter (PC) is reset, and the system clock defaults to an internal oscillator. The Watchdog Timer is enabled, and program execution begins at location 0x0000.

Reset sources on the device include the following:

- · Power-on reset
- External reset pin
- · Comparator reset
- Software-triggered reset
- · Supply monitor reset (monitors VDD supply)
- · Watchdog timer reset
- · Missing clock detector reset
- · Flash error reset

3.9 Debugging

The EFM8LB1 devices include an on-chip Silicon Labs 2-Wire (C2) debug interface to allow flash programming and in-system debugging with the production part installed in the end application. The C2 interface uses a clock signal (C2CK) and a bi-directional C2 data signal (C2D) to transfer information between the device and a host system. See the C2 Interface Specification for details on the C2 protocol.

3.10 Bootloader

All devices come pre-programmed with a UART0 bootloader. This bootloader resides in the code security page, which is the last page of code flash; it can be erased if it is not needed.

The byte before the Lock Byte is the Bootloader Signature Byte. Setting this byte to a value of 0xA5 indicates the presence of the bootloader in the system. Any other value in this location indicates that the bootloader is not present in flash.

When a bootloader is present, the device will jump to the bootloader vector after any reset, allowing the bootloader to run. The bootloader then determines if the device should stay in bootload mode or jump to the reset vector located at 0x0000. When the bootloader is not present, the device will jump to the reset vector of 0x0000 after any reset.

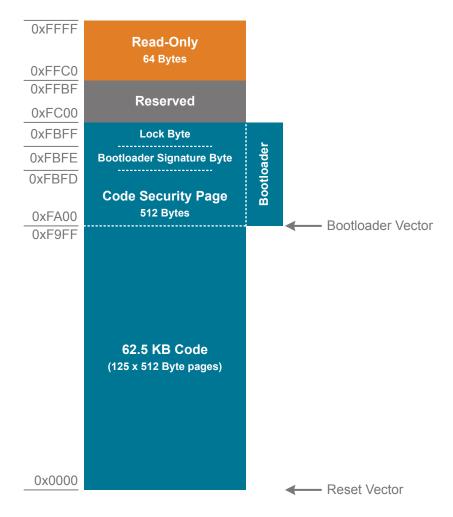


Figure 3.2. Flash Memory Map with Bootloader — 62.5 KB Devices

4.1.2 Power Consumption

Table 4.2. Power Consumption

Parameter	Symbol	Test Condition	Min	Тур	Max	Unit
Digital Core Supply Current						
Normal Mode-Full speed with code	I _{DD}	F _{SYSCLK} = 72 MHz ²	_	TBD	TBD	mA
executing from flash		F _{SYSCLK} = 24.5 MHz ²	_	4.5	TBD	mA
		F _{SYSCLK} = 1.53 MHz ²	_	615	TBD	μA
		F _{SYSCLK} = 80 kHz ³	_	155	TBD	μA
Idle Mode-Core halted with periph-	I _{DD}	F _{SYSCLK} = 72 MHz ²	_	TBD	TBD	mA
erals running		F _{SYSCLK} = 24.5 MHz ²	_	2.8	TBD	mA
		F _{SYSCLK} = 1.53 MHz ²	_	455	TBD	μA
		F _{SYSCLK} = 80 kHz ³	_	145	TBD	μA
Suspend Mode-Core halted and	I _{DD}	LFO Running	_	125	TBD	μA
nigh frequency clocks stopped, Supply monitor off.		LFO Stopped	_	120	TBD	μA
Snooze Mode-Core halted and	I _{DD}	LFO Running	_	26	TBD	μA
nigh frequency clocks stopped. Regulator in low-power state, Supply monitor off.		LFO Stopped	_	21	TBD	μА
Stop Mode—Core halted and all clocks stopped,Internal LDO On, Supply monitor off.	I _{DD}		_	120	TBD	μA
Shutdown Mode—Core halted and all clocks stopped,Internal LDO Off, Supply monitor off.	I _{DD}		_	0.2	_	μА
Analog Peripheral Supply Currents	1			1	1	
High-Frequency Oscillator 0	I _{HFOSC0}	Operating at 24.5 MHz, $T_A = 25 ^{\circ}\text{C}$	_	55	_	μА
High-Frequency Oscillator 1	I _{HFOSC1}	Operating at 72 MHz,	_	TBD	_	μA
ng	111 0301	T _A = 25 °C				,
_ow-Frequency Oscillator	I _{LFOSC}	Operating at 80 kHz,		5	_	μA
		T _A = 25 °C				
ADC0 High Speed Mode ⁴	I _{ADC}	1 Msps, 12-bit conversions	_	TBD	TBD	μA
		Normal bias settings				
		V _{DD} = 3.0 V				
ADC0 Low Power Mode ⁴	I _{ADC}	TBD	_	TBD	TBD	μA
nternal ADC0 Reference ⁵	I _{VREFFS}	Normal Power Mode	_	680	790	μA
		Low Power Mode	_	160	210	μA
On-chip Precision Reference	I _{VREFP}		_	75	_	μΑ

Parameter	Symbol	Test Condition	Min	Тур	Max	Unit			
Power Supply Rejection Ratio	PSRR _{ADC}		_	TBD	_	dB			
DC Performance									
Integral Nonlinearity	INL	14 Bit Mode	_	TBD	_	LSB			
		12 Bit Mode	-1.4	TBD	+1.4	LSB			
		10 Bit Mode	_	TBD	_	LSB			
Differential Nonlinearity (Guaran-	DNL	14 Bit Mode	_	TBD	_	LSB			
teed Monotonic)		12 Bit Mode	_	TBD	0.9	LSB			
		10 Bit Mode	_	TBD	_	LSB			
Offset Error	E _{OFF}	14 Bit Mode	_	TBD	_	LSB			
		12 Bit Mode	-2	TBD	2	LSB			
		10 Bit Mode	_	TBD	_	LSB			
Offset Temperature Coefficient	TC _{OFF}		_	TBD	_	LSB/°C			
Slope Error	E _M	14 Bit Mode	_	TBD	_	%			
		12 Bit Mode	_	TBD	TBD	%			
		10 Bit Mode	_	TBD	_	%			
Dynamic Performance 10 kHz Sine	Wave Input	1 dB below full scale, Max throughput	t, using AGN	D pin	1	1			
Signal-to-Noise	SNR	14 Bit Mode	_	TBD	_	dB			
		12 Bit Mode	TBD	TBD	_	dB			
		10 Bit Mode	_	TBD	_	dB			
Signal-to-Noise Plus Distortion	SNDR	14 Bit Mode	_	TBD	_	dB			
		12 Bit Mode	TBD	TBD	_	dB			
		10 Bit Mode	_	TBD	_	dB			
Total Harmonic Distortion (Up to	THD	14 Bit Mode	_	TBD	_	dB			
5th Harmonic)		12 Bit Mode	_	TBD	_	dB			
		10 Bit Mode	_	TBD	_	dB			
Spurious-Free Dynamic Range	SFDR	14 Bit Mode	_	TBD	_	dB			
		12 Bit Mode	_	TBD	_	dB			
		10 Bit Mode	_	TBD	_	dB			

Note:

- 1. This time is equivalent to four periods of a clock running at 18 MHz + 2%.
- 2. Conversion Time does not include Tracking Time. Total Conversion Time is:

Total Conversion Time = $[RPT \times (ADTK + NUMBITS + 1) \times T(SARCLK)] + (T(ADCCLK) \times 4)$

where RPT is the number of conversions represented by the ADRPT field and ADCCLK is the clock selected for the ADC.

3. Absolute input pin voltage is limited by the $\ensuremath{\text{V}_{\text{IO}}}$ supply.

4.1.13 Comparators

Table 4.13. Comparators

Parameter	Symbol	Test Condition	Min	Тур	Max	Unit
Response Time, CPMD = 00	t _{RESP0}	+100 mV Differential	_	100	_	ns
(Highest Speed)		-100 mV Differential	_	150	_	ns
Response Time, CPMD = 11 (Low-	t _{RESP3}	+100 mV Differential	_	1.5	_	μs
est Power)		-100 mV Differential	_	3.5	_	μs
Positive Hysteresis	HYS _{CP+}	CPHYP = 00	_	0.4	_	mV
Mode 0 (CPMD = 00)		CPHYP = 01	_	8	_	mV
		CPHYP = 10	_	16	_	mV
		CPHYP = 11	_	32	_	mV
Negative Hysteresis	HYS _{CP} -	CPHYN = 00	_	-0.4	_	mV
Mode 0 (CPMD = 00)		CPHYN = 01	_	-8	_	mV
		CPHYN = 10	_	-16	_	mV
		CPHYN = 11	_	-32	_	mV
Positive Hysteresis	HYS _{CP+}	CPHYP = 00	_	0.5	_	mV
Mode 1 (CPMD = 01)		CPHYP = 01	_	6	_	mV
		CPHYP = 10	_	12	_	mV
		CPHYP = 11	_	24	_	mV
Negative Hysteresis	HYS _{CP} -	CPHYN = 00	_	-0.5	_	mV
Mode 1 (CPMD = 01)		CPHYN = 01	_	-6	_	mV
		CPHYN = 10	_	-12	_	mV
		CPHYN = 11	_	-24	_	mV
Positive Hysteresis	HYS _{CP+}	CPHYP = 00	_	0.7	_	mV
Mode 2 (CPMD = 10)		CPHYP = 01	_	4.5	_	mV
		CPHYP = 10	_	9	_	mV
		CPHYP = 11	_	18	_	mV
Negative Hysteresis	HYS _{CP} -	CPHYN = 00	_	-0.6	_	mV
Mode 2 (CPMD = 10)		CPHYN = 01	_	-4.5	_	mV
		CPHYN = 10	_	-9	_	mV
		CPHYN = 11	_	-18	_	mV
Positive Hysteresis	HYS _{CP+}	CPHYP = 00	_	1.5	_	mV
Mode 3 (CPMD = 11)		CPHYP = 01	_	4	_	mV
		CPHYP = 10	_	8	_	mV
		CPHYP = 11	_	16	_	mV

4.2 Thermal Conditions

Table 4.16. Thermal Conditions

Parameter	Symbol	Test Condition	Min	Тур	Max	Unit
Thermal Resistance	θ_{JA}	QFN24 Packages	_	TBD	_	°C/W
		QFN32 Packages	_	TBD	_	°C/W
		QFP32 Packages	_	80	_	°C/W
		QSOP24 Packages	_	65	_	°C/W

Note:

4.3 Absolute Maximum Ratings

Stresses above those listed in Table 4.17 Absolute Maximum Ratings on page 27 may cause permanent damage to the device. This is a stress rating only and functional operation of the devices at those or any other conditions above those indicated in the operation listings of this specification is not implied. Exposure to maximum rating conditions for extended periods may affect device reliability. For more information on the available quality and reliability data, see the Quality and Reliability Monitor Report at http://www.silabs.com/support/quality/pages/default.aspx.

Table 4.17. Absolute Maximum Ratings

Parameter	Symbol	Test Condition	Min	Max	Unit
Ambient Temperature Under Bias	T _{BIAS}		-55	125	°C
Storage Temperature	T _{STG}		-65	150	°C
Voltage on VDD	V_{DD}		GND-0.3	4.2	V
Voltage on VIO ²	V _{IO}		GND-0.3	V _{DD} +0.3	V
Voltage on I/O pins or RSTb, excluding	V _{IN}	V _{IO} > TBD V	GND-0.3	TBD	V
P2.0-P2.3 (QFN24 and QSOP24) or P3.0-P3.3 (QFN32 and QFP32)		V _{IO} < TBD V	GND-0.3	TBD	V
Voltage on P2.0-P2.3 (QFN24 and QSOP24) or P3.0-P3.3 (QFN32 and QFP32)	V _{IN}		GND-0.3	V _{DD} +0.3	V
Total Current Sunk into Supply Pin	I _{VDD}		_	400	mA
Total Current Sourced out of Ground Pin	I _{GND}		400	_	mA
Current Sourced or Sunk by any I/O Pin or RSTb	I _{IO}		-100	100	mA

- 1. Exposure to maximum rating conditions for extended periods may affect device reliability.
- 2. In certain package configurations, the VIO and VDD supplies are bonded to the same pin.

^{1.} Thermal resistance assumes a multi-layer PCB with any exposed pad soldered to a PCB pad.

5. Typical Connection Diagrams

5.1 Power

Figure 5.1 Power Connection Diagram on page 28 shows a typical connection diagram for the power pins of the device.

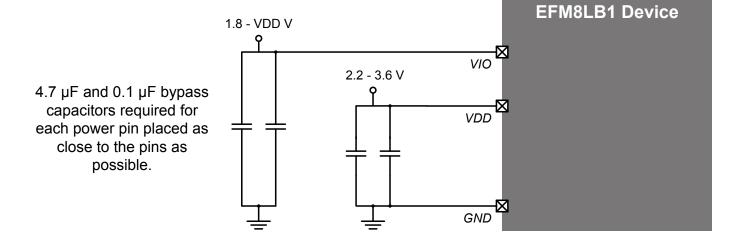


Figure 5.1. Power Connection Diagram

Pin Number	Pin Name	Description	Crossbar Capability	Additional Digital Functions	Analog Functions
28	P0.5	Multifunction I/O	Yes	P0MAT.5	ADC0.3
				INT0.5	CMP0P.3
				INT1.5	CMP0N.3
				UART0_RX	
				CLU0B.10	
				CLU1A.9	
29	P0.4	Multifunction I/O	Yes	P0MAT.4	ADC0.2
				INT0.4	CMP0P.2
				INT1.4	CMP0N.2
				UART0_TX	
				CLU0A.10	
				CLU1A.8	
30	P0.3	Multifunction I/O	Yes	P0MAT.3	XTAL2
				EXTCLK	
				INT0.3	
				INT1.3	
				CLU0B.9	
				CLU2B.10	
				CLU3A.9	
31	P0.2	Multifunction I/O	Yes	P0MAT.2	XTAL1
				INT0.2	ADC0.1
				INT1.2	CMP0P.1
				CLU0OUT	CMP0N.1
				CLU0A.9	
				CLU2B.8	
				CLU3A.8	
32	P0.1	Multifunction I/O	Yes	P0MAT.1	ADC0.0
				INT0.1	CMP0P.0
				INT1.1	CMP0N.0
				CLU0B.8	AGND
				CLU2A.9	
				CLU3B.9	
Center	GND	Ground			

Pin	Pin Name	Description	Crossbar Capability	Additional Digital	Analog Functions
Number				Functions	
6	P3.7 /	Multifunction I/O /			
	C2D	C2 Debug Data			
7	P3.3	Multifunction I/O			DAC3
8	P3.2	Multifunction I/O			DAC2
9	P3.1	Multifunction I/O			DAC1
10	P3.0	Multifunction I/O			DAC0
11	P2.6	Multifunction I/O			ADC0.19
					CMP1P.8
					CMP1N.8
12	P2.5	Multifunction I/O		CLU3OUT	ADC0.18
					CMP1P.7
					CMP1N.7
13	P2.4	Multifunction I/O			ADC0.17
					CMP1P.6
					CMP1N.6
14	P2.3	Multifunction I/O	Yes	P2MAT.3	ADC0.16
				CLU1B.15	CMP1P.5
				CLU2B.15	CMP1N.5
				CLU3A.15	
15	P2.2	Multifunction I/O	Yes	P2MAT.2	ADC0.15
				CLU2OUT	CMP1P.4
				CLU1A.15	CMP1N.4
				CLU2B.14	
				CLU3A.14	
16	P2.1	Multifunction I/O	Yes	P2MAT.1	ADC0.14
				I2C0_SCL	CMP1P.3
				CLU1B.14	CMP1N.3
				CLU2A.15	
				CLU3B.15	
17	P2.0	Multifunction I/O	Yes	P2MAT.0	CMP1P.2
				I2C0_SDA	CMP1N.2
				CLU1A.14	
				CLU2A.14	
				CLU3B.14	

Pin Number	Pin Name	Description	Crossbar Capability	Additional Digital Functions	Analog Functions
18	P1.2	Multifunction I/O	Yes	P1MAT.2	ADC0.8
				CLU0A.13	
				CLU1A.11	
				CLU2B.10	
				CLU3A.12	
				CLU3B.13	
19	P1.1	Multifunction I/O	Yes	P1MAT.1	ADC0.7
				CLU0B.12	
				CLU1B.10	
				CLU2A.11	
				CLU3B.12	
20	P1.0	Multifunction I/O	Yes	P1MAT.0	ADC0.6
				CLU0A.12	
				CLU1A.10	
				CLU2A.10	
21	P0.7	Multifunction I/O	Yes	P0MAT.7	ADC0.5
				INT0.7	CMP0P.5
				INT1.7	CMP0N.5
				CLU1OUT	CMP1P.1
				CLU0B.11	CMP1N.1
				CLU1B.9	
				CLU3A.11	
22	P0.6	Multifunction I/O	Yes	P0MAT.6	ADC0.4
				CNVSTR	CMP0P.4
				INT0.6	CMP0N.4
				INT1.6	CMP1P.0
				CLU0A.11	CMP1N.0
				CLU1B.8	
				CLU3A.10	
23	P0.5	Multifunction I/O	Yes	P0MAT.5	ADC0.3
				INT0.5	CMP0P.3
				INT1.5	CMP0N.3
				UART0_RX	
				CLU0B.10	
				CLU1A.9	

Pin Number	Pin Name	Description	Crossbar Capability	Additional Digital Functions	Analog Functions
24	P0.4	Multifunction I/O	Yes	P0MAT.4	ADC0.2
				INT0.4	CMP0P.2
				INT1.4	CMP0N.2
				UART0_TX	
				CLU0A.10	
				CLU1A.8	

7. QFN32 Package Specifications

7.1 QFN32 Package Dimensions

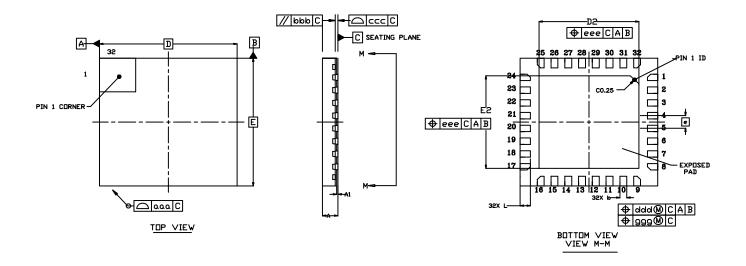


Figure 7.1. QFN32 Package Drawing

Table 7.1. QFN32 Package Dimensions

Dimension	Min	Тур	Max
A	0.45	0.50	0.55
A1	0.00	0.035	0.05
b	0.15	0.20	0.25
D	4.00 BSC.		
D2	2.80	2.90	3.00
е	0.40 BSC.		
E	4.00 BSC.		
E2	2.80	2.90	3.00
L	0.20	0.30	0.40
aaa	_	_	0.10
bbb	_	_	0.10
ccc	_	_	0.08
ddd	_	_	0.10
eee		_	0.10
999	_	_	0.05

Dimension Min Typ Max

- 1. All dimensions shown are in millimeters (mm) unless otherwise noted.
- 2. Dimensioning and Tolerancing per ANSI Y14.5M-1994.
- 3. This drawing conforms to JEDEC Solid State Outline MO-220.
- 4. Recommended card reflow profile is per the JEDEC/IPC J-STD-020C specification for Small Body Components.

8. QFP32 Package Specifications

8.1 QFP32 Package Dimensions

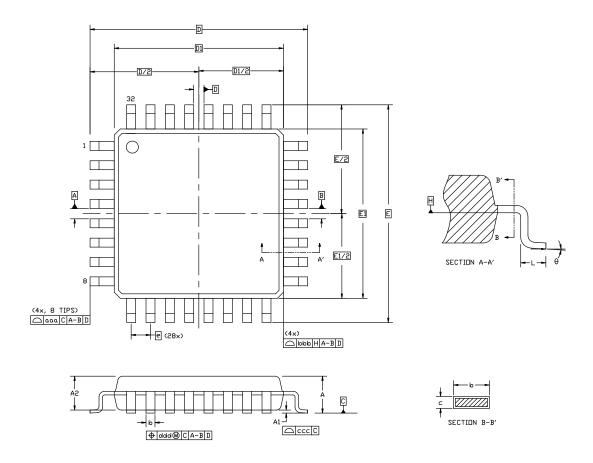


Figure 8.1. QFP32 Package Drawing

Table 8.1. QFP32 Package Dimensions

Dimension	Min	Тур	Max
Α	_	_	1.20
A1	0.05	_	0.15
A2	0.95	1.00	1.05
b	0.30	0.37	0.45
С	0.09	_	0.20
D	9.00 BSC		
D1	7.00 BSC		
е	0.80 BSC		
E	9.00 BSC		
E1	7.00 BSC		
L	0.50	0.60	0.70

Dimension	Min	Тур	Max
е	0.40 BSC		
e1	0.45 BSC		
J	1.60	1.70	1.80
К	1.60	1.70	1.80
L	0.35	0.40	0.45
L1	0.25	0.30	0.35
aaa	_	0.10	_
bbb	_	0.10	_
ccc	_	0.08	_
ddd	_	0.1	_
eee	_	0.1	_

- 1. All dimensions shown are in millimeters (mm) unless otherwise noted.
- 2. Dimensioning and Tolerancing per ANSI Y14.5M-1994.
- 3. This drawing conforms to JEDEC Solid State Outline MO-248 but includes custom features which are toleranced per supplier designation.
- 4. Recommended card reflow profile is per the JEDEC/IPC J-STD-020 specification for Small Body Components.

10.2 QSOP24 PCB Land Pattern

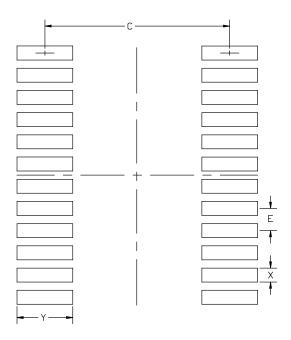


Figure 10.2. QSOP24 PCB Land Pattern Drawing

Table 10.2. QSOP24 PCB Land Pattern Dimensions

Dimension	Min	Мах	
С	5.20	5.30	
Е	0.635 BSC		
Х	0.30	0.40	
Y	1.50	1.60	

- 1. All dimensions shown are in millimeters (mm) unless otherwise noted.
- 2. This land pattern design is based on the IPC-7351 guidelines.
- 3. All metal pads are to be non-solder mask defined (NSMD). Clearance between the solder mask and the metal pad is to be 60 μ m minimum, all the way around the pad.
- 4. A stainless steel, laser-cut and electro-polished stencil with trapezoidal walls should be used to assure good solder paste release.
- 5. The stencil thickness should be 0.125 mm (5 mils).
- 6. The ratio of stencil aperture to land pad size should be 1:1 for all perimeter pads.
- 7. A No-Clean, Type-3 solder paste is recommended.
- 8. The recommended card reflow profile is per the JEDEC/IPC J-STD-020 specification for Small Body Components.











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